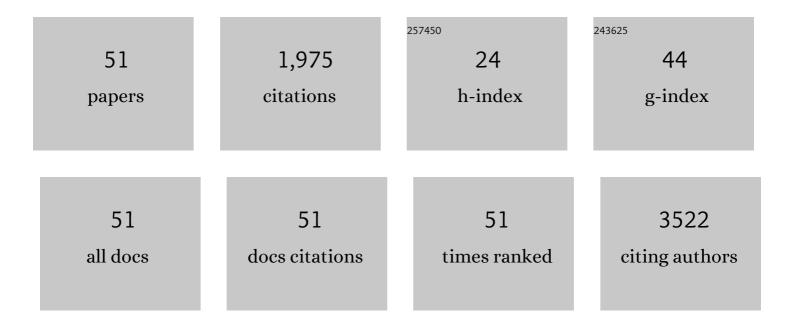
Abhay A Sagade

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Copper sulphide (CuxS) as an ammonia gas sensor working at room temperature. Sensors and Actuators B: Chemical, 2008, 133, 135-143.	7.8	230
2	Ultrafast response humidity sensor using supramolecular nanofibre and its application in monitoring breath humidity and flow. Scientific Reports, 2014, 4, 4103.	3.3	224
3	Growth and characterization of tin disulfide (SnS2) thin film deposited by successive ionic layer adsorption and reaction (SILAR) technique. Journal of Alloys and Compounds, 2007, 436, 421-426.	5.5	174
4	Ultra-sensitive Hall sensors based on graphene encapsulated in hexagonal boron nitride. Applied Physics Letters, 2015, 106, .	3.3	127
5	Highly air stable passivation of graphene based field effect devices. Nanoscale, 2015, 7, 3558-3564.	5.6	120
6	Experimental verification of electro-refractive phase modulation in graphene. Scientific Reports, 2015, 5, 10967.	3.3	83
7	Effect of annealing on structural and optical properties of zinc oxide thin film deposited by successive ionic layer adsorption and reaction technique. Journal of Alloys and Compounds, 2009, 469, 56-60.	5.5	77
8	Highâ€Mobility Field Effect Transistors Based on Supramolecular Charge Transfer Nanofibres. Advanced Materials, 2013, 25, 559-564.	21.0	74
9	A comparative study of the physical properties of CdS, Bi2S3 and composite CdS–Bi2S3 thin films for photosensor application. Sensors and Actuators A: Physical, 2007, 140, 207-214.	4.1	49
10	Engineering the Photoresponse of InAs Nanowires. ACS Applied Materials & Interfaces, 2017, 9, 43993-44000.	8.0	49
11	Flexible and Semitransparent Strain Sensors Based on Micromolded Pd Nanoparticle–Carbon μ-Stripes. ACS Applied Materials & Interfaces, 2011, 3, 2173-2178.	8.0	48
12	A charge transfer single crystal field effect transistor operating at low voltages. Chemical Communications, 2013, 49, 5847.	4.1	48
13	Parameter Space of Atomic Layer Deposition of Ultrathin Oxides on Graphene. ACS Applied Materials & Interfaces, 2016, 8, 30564-30575.	8.0	47
14	100 GHz zinc oxide Schottky diodes processed from solution on a wafer scale. Nature Electronics, 2020, 3, 718-725.	26.0	45
15	Infrared transparent graphene heater for silicon photonic integrated circuits. Optics Express, 2016, 24, 7871.	3.4	44
16	Enhancement in sensitivity of copper sulfide thin film ammonia gas sensor: Effect of swift heavy ion irradiation. Journal of Applied Physics, 2009, 105, .	2.5	40
17	Engineering of nanocrystalline cadmium sulfide thin films by using swift heavy ions. Journal Physics D: Applied Physics, 2007, 40, 4850-4854.	2.8	39
18	Encapsulation of graphene transistors and vertical device integration by interface engineering with atomic layer deposited oxide. 2D Materials, 2017, 4, 011008.	4.4	39

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19	Photoelectrochemical (PEC) studies on CdSe thin films electrodeposited from non-aqueous bath on different substrates. Bulletin of Materials Science, 2007, 30, 321-327.	1.7	38
20	Dynamic Selfâ€Assembly of Chargeâ€Transfer Nanofibers of Tetrathiafulvalene Derivatives with F ₄ TCNQ. Chemistry - A European Journal, 2011, 17, 12355-12361.	3.3	35
21	A physics-based model of gate-tunable metal–graphene contact resistance benchmarked against experimental data. 2D Materials, 2015, 2, 025006.	4.4	30
22	Low Resistive Edge Contacts to CVDâ€Grown Graphene Using a CMOS Compatible Metal. Annalen Der Physik, 2017, 529, 1600410.	2.4	29
23	Room temperature electrosynthesis of ZnSe thin films. Journal of Alloys and Compounds, 2009, 488, 157-162.	5.5	25
24	A low cost optical hydrogen sensing device using nanocrystalline Pd grating. International Journal of Hydrogen Energy, 2012, 37, 9443-9449.	7.1	25
25	Modifications of structural, optical and electrical properties of nanocrystalline bismuth sulphide by using swift heavy ions. Current Applied Physics, 2009, 9, 374-379.	2.4	24
26	Structural damage studies in conducting indium-tin oxide (ITO) thin films induced by Au8+ swift heavy ions (SHI) irradiation. Vacuum, 2007, 82, 39-44.	3.5	22
27	Graphene-based nanolaminates as ultra-high permeation barriers. Npj 2D Materials and Applications, 2017, 1, .	7.9	21
28	Growth and characterization of CdZn(S1â^'xSex)2 alloy film deposited by solution growth technique. Journal of Alloys and Compounds, 2007, 436, 400-406.	5.5	18
29	Atomic layer deposited oxide films as protective interface layers for integrated graphene transfer. Nanotechnology, 2017, 28, 485201.	2.6	18
30	Electronic properties of CVD graphene: The role of grain boundaries, atmospheric doping, and encapsulation by ALD. Physica Status Solidi (B): Basic Research, 2016, 253, 2321-2325.	1.5	17
31	On the origin of contact resistances in graphene devices fabricated by optical lithography. Applied Physics A: Materials Science and Processing, 2016, 122, 1.	2.3	17
32	Gigantic irradiation effect of 100ÂMeV Au8+swift heavy ions on the copper sulfide thin films with different chemical compositions. Radiation Effects and Defects in Solids, 2007, 162, 77-85.	1.2	16
33	Ultrafast Direct Ablative Patterning of HOPG by Single Laser Pulses to Produce Graphene Ribbons. Advanced Functional Materials, 2011, 21, 3836-3842.	14.9	15
34	Defining Switching Efficiency of Multilevel Resistive Memory with PdO as an Example. Advanced Electronic Materials, 2016, 2, 1500286.	5.1	14
35	Effect of high electronic energy loss of 100MeV gold heavy ions in copper chalcogenides (CuX, X=S,) Tj ETQq1 1 1653-1658.	0.784314 3.1	ł rgBT /Over 8
36	On the Contact Optimization of ALD-Based MoS ₂ FETs: Correlation of Processing Conditions and Interface Chemistry with Device Electrical Performance. ACS Applied Electronic Materials, 2021, 3, 3185-3199.	4.3	8

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37	Metal-organic molecular device for non-volatile memory storage. Applied Physics Letters, 2014, 105, .	3.3	7
38	Intricate nature of Pd nanocrystal–hydrogen interaction investigated using thermolysed Pd hexadecylthiolate films. Sensors and Actuators B: Chemical, 2010, 149, 345-351.	7.8	6
39	Dirac-Point Shift by Carrier Injection Barrier in Graphene Field-Effect Transistor Operation at Room Temperature. ACS Applied Materials & Interfaces, 2018, 10, 10618-10621.	8.0	5
40	Templating effect of single-layer graphene supported by an insulating substrate on the molecular orientation of lead phthalocyanine. Beilstein Journal of Nanotechnology, 2020, 11, 814-820.	2.8	4
41	On the indentation-assisted phase engineered Si for solar applications. Scripta Materialia, 2020, 184, 19-23.	5.2	4
42	Direct Micromolding of Pd μ-Stripes for Electronic Applications. Journal of Nanoscience and Nanotechnology, 2011, 11, 152-157.	0.9	3
43	Towards a Graphene-Based Low Intensity Photon Counting Photodetector. Sensors, 2016, 16, 1351.	3.8	3
44	A carbon nanotube–graphene nanoribbon seamless junction transistor. Nanoscale Advances, 2020, 2, 659-663.	4.6	3
45	Electrical characterization of 100ÂMeV heavy ion irradiated Au/p-Cu _{1.4} S Schottky barrier diodes. Radiation Effects and Defects in Solids, 2009, 164, 31-37.	1.2	1
46	Graphene-based MMIC process development and RF passives design. , 2015, , .		1
47	Effect of Different Substrates on Performance of Copper Sulfide Thin Film Ammonia Gas Sensor. Sensor Letters, 2009, 7, 550-556.	0.4	1
48	Evidence of Phonon Condensers at Nanoscale. , 2009, , .		0
49	Zinc Oxide Nano Particle Grown By Soft Solution Route at Room Temperature. , 2009, , .		0
50	Working towards graphene-based detectors for high sensitivity photodetection. , 2016, , .		0
51	Experimental demonstration of electro-refractive phase modulators based on graphene. , 2015, , .		0